



## Temperature and Spectral Effects on Perovskite Solar Cells: A SCAPS-1D Simulation Study

Haneefa Yahya Najem<sup>1\*</sup>, Raad A. Rasool<sup>2</sup>, Mohanad Natheer Zubair Mala<sup>3</sup>, Ali M. Saadi<sup>4\*</sup>

<sup>1</sup> Department of Radiology Techniques, Mosul Medical Technical Institute, Northern Technical University, Mosul 41001, Iraq

<sup>2</sup> Department of Optical Techniques, College of Health and Medical Technologies, Al-Noor University College, Mosul 41001, Iraq

<sup>3</sup> Department of Optometry Techniques, Mosul Medical Technical Institute, Northern Technical University, Mosul 41001, Iraq

<sup>4</sup> Department of Animal Production Techniques, Technical Agricultural College, Northern Technical University, Mosul 41001, Iraq

Corresponding Author Email: [ali.mohammed@ntu.edu.iq](mailto:ali.mohammed@ntu.edu.iq)

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### ABSTRACT

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#### Keywords:

SCAPS-1D modeling, perovskite-based solar cells, thermal performance, spectral response, stability

This study indicates that SCAPS-1D software simulated perovskite solar cells to monitor their temperature and light wavelength reactions under monochromatic light at 400 nm, 450 nm, and 500 nm. The short-circuit current density ( $J_{sc}$ ), open-circuit voltage ( $V_{oc}$ ), fill factor (FF %), and power conversion efficiency (PCE) were assessed across a temperature range of 290K to 340K. At 290K, the peak PCE values attained were 25.15% at 450 nm, 24.71% at 500 nm, and 22.30% at 400 nm; however, the open-circuit voltage ( $V_{oc}$ ) diminished by almost 20% on average across all wavelengths when the temperature rose to 340K. Longer wavelengths, particularly at 450 nm and 500 nm, enhanced performance marginally—by approximately 2–3% in power conversion efficiency—relative to 400nm, owing to greater light penetration and less surface recombination. Nonetheless, elevated temperatures markedly diminished  $V_{oc}$ , FF %, and PCE, chiefly due to heightened recombination and reverse saturation current. At 300K, the fill factor (FF %) reached a maximum of 85.3% for 450 nm, 85.3% for 500 nm, and 85.0% for 400 nm, thereafter decreasing to approximately 84.0–84.5%. The results validate that heat degradation and spectrum response are critical determinants influencing the performance of perovskite solar cells. This study underscores the necessity of enhancing thermal stability and spectrum absorption to get high-efficiency and stable perovskite solar cells.

## 1. INTRODUCTION

The rapid advancement of photovoltaic (PV) technology has positioned perovskite solar cells (PSCs) as the foremost next-generation solar energy conversion devices. This is due to its ease of fabrication and high power conversion efficiency (PCE) [1].

Perovskite solar cells (PSCs), identified in the early 2010s, exhibit variable bandgap properties alongside enhanced optoelectronic performance, attaining efficiencies similar to conventional silicon solar cells [2, 3]. The temperature (T) and the incoming light spectrum ( $\lambda$ ) significantly influence the performance and longevity of PSC devices. Further investigation is necessary to enhance our understanding of them, which will facilitate improved sales and development. The performance of perovskite solar cells (PSCs) across various spectra is influenced by their morphology and bandgap (Eg). This describes the process by which various wavelengths of light can be converted into electricity. The bandgap (Eg) of perovskite materials typically ranges from 1.1 eV to 2.3 eV and makes available the spectral match with the solar spectrum of the emitted light, allowing for an implementation in a tandem cell configuration [4, 5]. The spectrum of sunlight,

which varies based on geographic location and weather conditions, directly influences the operational efficiency and overall performance of the device. The external quantum efficiency (EQE) spectrum is a critical method for analyzing the variation of response with wavelength.

The fundamental photovoltaic process in perovskite solar cells (PSCs) entails the separation and movement of electron-hole pairs ( $e^-h^+$ ), resulting in the generation of current. The Shockley-Queisser (SQ) limit, which is the theoretical maximum efficiency threshold of 34.9% for concentrated sunlight and 32.6% for non-concentrated sunlight, is contingent upon the solar spectrum and the band-gap (Eg) [6, 7]. For an optimal device under 1.5G light (1000 W/m<sup>2</sup>), the greatest theoretical efficiency ( $\eta_{max}$ ) can be expressed as:

$$\eta_{max} = \frac{q \times V_{oc} \times J_{sc} \times FF}{P_{in}}$$

where,

$q$ : elementary charge ( $1.602 \times 10^{-19}$  C)

$V_{oc}$ : Open-circuit voltage (depends on bandgap (Eg))

$J_{sc}$ : Short-circuit current density (depends on (Eg))

$FF$ : Fill factor (depends on ( $V_{oc}$ ))

$P_{in}$ : Incident solar power density

$$\eta_{max(Eg)} \approx E_g^2 \cdot e^{\frac{-E_g}{E_0}}$$

where,

$$E_0 \approx 0.9 \text{ eV}$$

This expression reflects the trade-off between increasing voltage ( $V_{oc}$ ) (with higher  $E_g$ ) and decreasing current  $J_{sc}$  (fewer photons absorbed). The optimum bandgap for maximum efficiency is  $\approx 1.34 \text{ eV}$ , yielding  $\eta_{max} \approx 33.7\%$  [8].

The temperature dependence of ( $V_{oc}$ ) is given by:

$$V_{oc}(T) = \frac{kB T}{q} \ln \left( \frac{J_{sc}}{J_o(T)} + 1 \right)$$

where,

$kB$ : Boltzmann constant ( $1.38 \times 10^{-23} \text{ J/K}$ ).

$T$ : Absolute temperature (K).

$J_{sc}$ : Short-circuit current density (weakly dependent on  $t$ ).

$J_o(T)$ : Temperature-dependent reverse saturation current density [9-11].

Recent advances in bandgap engineering and spectral tuning have enhanced the efficiency and thermal stability of PSCs. Techniques such as compositional texture engineering minimize phase segregation, enabling stable wide-bandgap perovskites with PCEs  $> 20\%$  and the superior operational lifetimes under thermal stress [12-14]. Meanwhile, advancements in manufacturing processes such as gas-quenched crystal growth have also improved crystal quality and lower defect densities, thus lessening performance losses from temperature ( $T$ ) and spectral variation ( $\lambda$ ) [15]. This study investigates the coupled effects of temperature ( $T$ ) and spectrum ( $\lambda$ ) on PSCs performance using SCAPS-1D simulation, of analyzing their impact on fill factor (FF) and efficiency ( $\eta$ ).

## 2. MATERIALS AND METHODS

### 2.1 Device modeling and structure

We modeled a generic thin-film perovskite solar cell using the SCAPS-1D simulation software. The device structure consisted of several layers arranged as FTO/CdS/ $\text{CH}_3\text{NH}_3\text{PbI}_3$ /CuO, as shown in Figure 1.

The material parameters, such as layer thicknesses, doping concentrations, bandgap energies, permittivity, and defect densities, were chosen according to standard values found in the literature and are presented in Table 1.

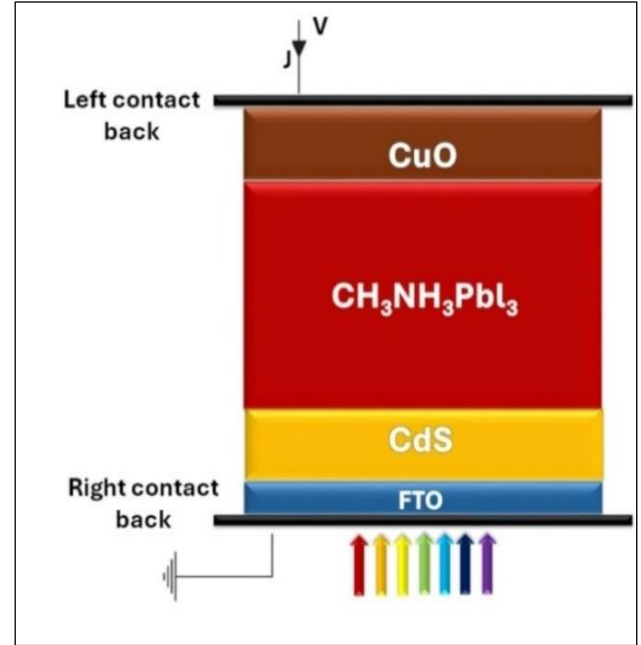


Figure 1. SCAPS-1D program for the cell used

Table 1. Material parameters used in the solar cell simulation

Parameter/Unit	FTO	CdS	$\text{CH}_3\text{NH}_3\text{PbI}_3$ (Perovskite)	CuO
Thickness $\mu\text{m}$	0.01	1.2	3.2	1.2
Bandgap eV	3.2	2.45	1.55	1.51
Electron Affinity eV	4.4	4.45	3.9	4.07
Relative permittivity	9	10	6.5	18.1
effective density of states CB $1/\text{cm}^3$	$1.20 \times 10^{18}$	$1.00 \times 10^{18}$	$2.20 \times 10^{17}$	$3.10 \times 10^{17}$
effective density of states V.B $1/\text{cm}^3$	$7.80 \times 10^{18}$	$1.50 \times 10^{15}$	$1.80 \times 10^{17}$	$5.50 \times 10^{17}$
Electron thermal velocity cm/s	$1.00 \times 10^7$	$1.00 \times 10^7$	$1.00 \times 10^7$	$1.00 \times 10^7$
Hole thermal velocity cm/s	$1.00 \times 10^7$	$1.00 \times 10^7$	$1.00 \times 10^7$	$1.00 \times 10^7$
Electron Mobility $\text{cm}^2/\text{V}\cdot\text{s}$	20	50	2	20
Hole Mobility $\text{cm}^2/\text{V}\cdot\text{s}$	100	20	2	10
Shallow uniform donor density Nd $1/\text{cm}^3$	$1.00 \times 10^{19}$	$1.00 \times 10^{16}$	0	0
Shallow uniform acceptor density Na $1/\text{cm}^3$	0	0	$1.00 \times 10^{19}$	$1.00 \times 10^{17}$
Defect type	Single Donor	Single Donor	Single Acceptor	Single Acceptor

### 2.2 Illumination and wavelength selection

The solar cell was exposed to monochromatic light with an

intensity of 1 sun ( $1000 \text{ W/m}^2$ ). We chose three different wavelengths: 400 nm (blue), 450 nm (cyan), and 500 nm (green). This choice was made because these wavelengths are

important parts of the visible spectrum that affect how carriers are made and how deeply they can be absorbed in different ways.

Shorter wavelengths (400 nm) don't penetrate very far, so they make carriers close to the surface, which speeds up surface recombination.

Longer wavelengths (450 nm and 500 nm) penetrate more deeply, creating carriers more evenly, which affects charge transport and recombination in different ways.

This focused methodology enables a comprehensive analysis of spectral and thermal effects, free from the unnecessary complexities linked to the entire solar spectrum [16-18].

### 2.3 Temperature range and simulation settings

Simulations were performed throughout a temperature range of 290 K to 340 K in 10 K increments to assess the impact of temperature on photovoltaic parameters.

For each temperature and wavelength set, we obtained the current-voltage (I-V) behavior of the device [19, 20]. The fill factor (FF) was determined from the ratio of the maximum power output to the product of open-circuit voltage ( $V_{oc}$ ) and short-circuit current density ( $J_{sc}$ ), while the I-V curve supplied information regarding  $V_{oc}$  and  $J_{sc}$  [21, 22]. The fill factor (FF) was taken as the proportion of the maximum power output [19, 23].

All electrical quantities flow, voltages, etc. They are per unit area. This method is in line with the established PV analysis methods [22, 23].

### 2.4 SCAPS-1D simulation model

The SCAPS-1D program, which is free of charge to the research community, is described in the literature. The model is based on incorporating recombination mechanisms to solve the semiconductor Poisson and continuity equations inside the device. This equation is known as the Shockley diode equation with the photo-generated current and describes the current-voltage (I-V) characteristics of a solar cell or p-n junction diode under illumination [24, 25].

$$J(V) = J_o \left( e^{\frac{qV}{nKT}} - 1 \right) - J_{ph}$$

### 2.5 External quantum efficiency (EQE)

Photovoltaic devices such as solar cells. It indicates the ability of a device to convert incident light (photons) into useful electrical current (electrons). EQE is defined as:

$$EQE = \frac{\text{Number of collected charge carriers}}{\text{Number of incident photons at wavelength } \lambda}$$

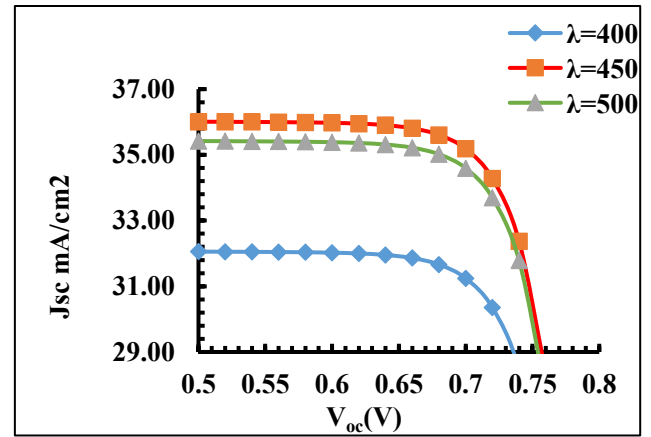
This is because EQE tells you how many charge carriers (most often electrons) you collect for each photon that hits at a given wavelength. The EQE value is dependent on the wavelength of light and provides an insight into the spectral response of the solar cell. This also means that the falling photons of different wavelengths are absorbed at different depths of the cell. The higher the EQE, the more the solar cell is effectively turning light into electricity at that wavelength. Through EQE spectrum analysis, material losses stemming from reflection, recombination, or incomplete absorption can be uncovered [26-28]. The parameters of the cell model used in this study are given in Table 1.

## 3. RESULTS AND DISCUSSION

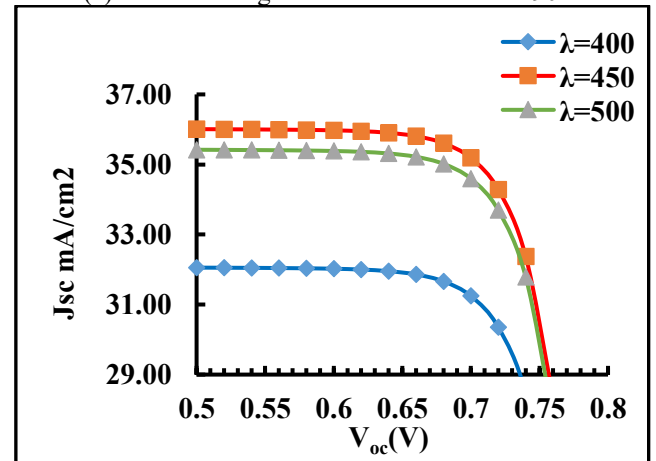
### 3.1 Current-voltage (I-V) characteristics and temperature influence

The simulated current-voltage (I-V) characteristics of the FTO/CdS/CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>/CuO perovskite solar cell under illumination wavelengths of 400 nm, 450 nm, and 500 nm were examined across a temperature range of 290 K to 340 K, as depicted in Figure 2(a-f). The open-circuit voltage ( $V_{oc}$ ) significantly declines with rising temperature, especially under illumination at 400 nm. The decline is mainly due to the rise in reverse saturation current density ( $J_o$ ), aligning with the diode equation  $\ln$  [29].

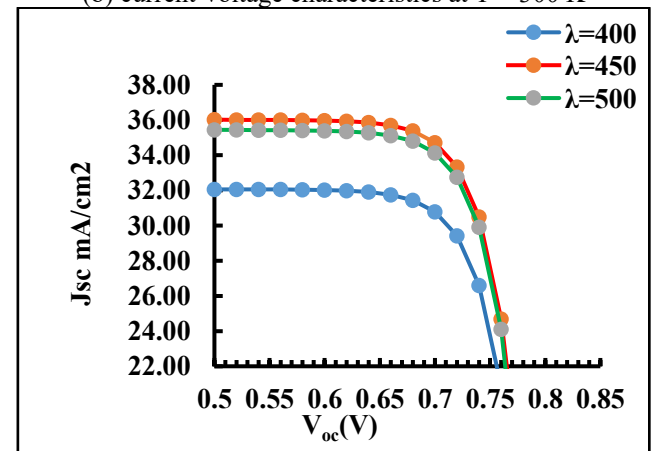
$$V_{oc} = \frac{nkT}{q} \ln \left( \frac{J_{sc}}{J_o} + 1 \right)$$



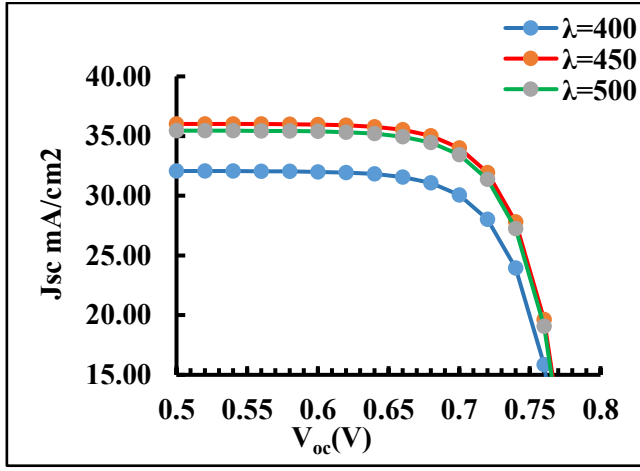
(a) current-voltage characteristics at T = 290 K



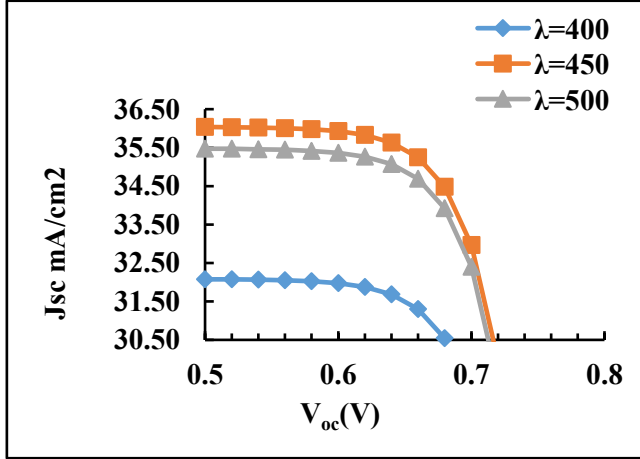
(b) current-voltage characteristics at T = 300 K



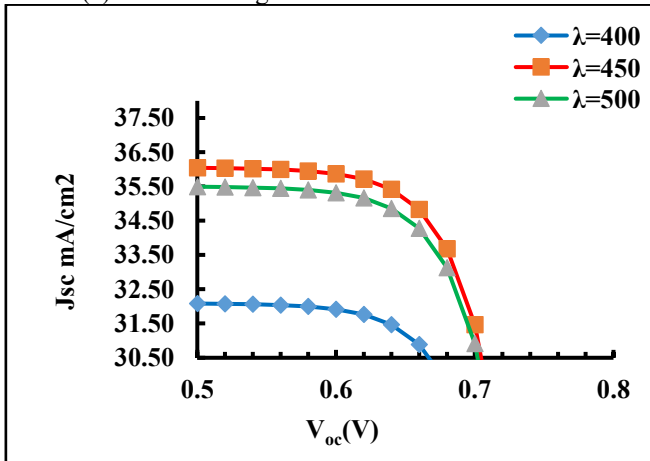
(c) current-voltage characteristics at T = 310 K



(d) current-voltage characteristics at T = 320 K



(e) current-voltage characteristics at T = 330 K



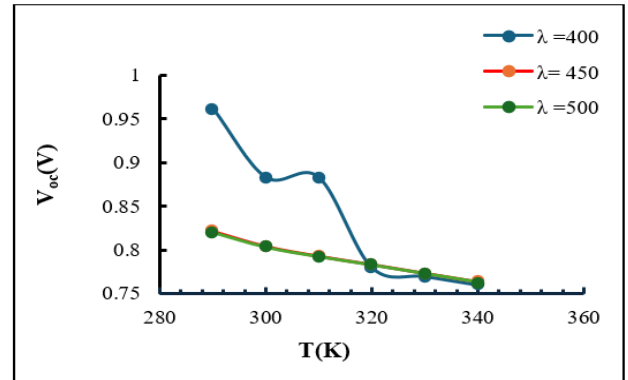
(f) current-voltage characteristics at T = 340 K

**Figure 2.** Simulated current-voltage (I-V) characteristics of the FTO/CdS/CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>/CuO perovskite solar cell under 400 nm, 450 nm, and 500 nm illumination across temperatures ranging from 290 K to 340 K

Such thermal behavior reflects enhanced recombination near the absorber interface, especially for shorter wavelengths with shallow absorption depth [30]. Among all conditions, 450 nm illumination yielded the highest  $V_{oc}$  and  $J_{sc}$ , indicating more favorable spectral absorption and charge transport properties [31]. Furthermore, distortion of the I-V curve at elevated temperatures (330-340 K) under 400 nm suggests increased series resistance or interface instability, possibly caused by degradation at the perovskite/transport layer interfaces [32, 33].

### 3.2 Open-circuit voltage ( $V_{oc}$ ) characteristics and temperature influence

The simulated open-circuit voltage ( $V_{oc}$ ) of the FTO/CdS/CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>/CuO perovskite solar cell under illumination wavelengths of 400 nm, 450 nm, and 500 nm was analyzed across temperatures ranging from 290 K to 340 K (Figure 3).  $V_{oc}$  exhibits a clear decrease with increasing temperature (Table 2). At 290 K, the maximum ( $V_{oc}$ ) values were approximately 0.96 V, 0.82 V, and 0.82 V for 400 nm, 450 nm, and 500 nm, respectively. By 340 K,  $V_{oc}$  dropped by nearly 20%, consistent with the exponential rise in reverse saturation current density ( $J_0$ ), explained by the Shockley diode equation [34-36]. The thermal activation of trap-assisted recombination increases with temperature, leading to degradation of  $V_{oc}$ .



**Figure 3.** Open-circuit voltage ( $V_{oc}$ ) characteristics and temperature influence

Notably, the degradation at 400 nm illumination is more significant due to carriers generated near the surface, prone to higher recombination losses because of shallower penetration depth [37]. Such thermal degradation is mainly and universally caused by an exponential increment of reverse saturation current density ( $J_0$ ) of a diode with temperature, by evaluating the Shockley diode equation in a wide temperature range.

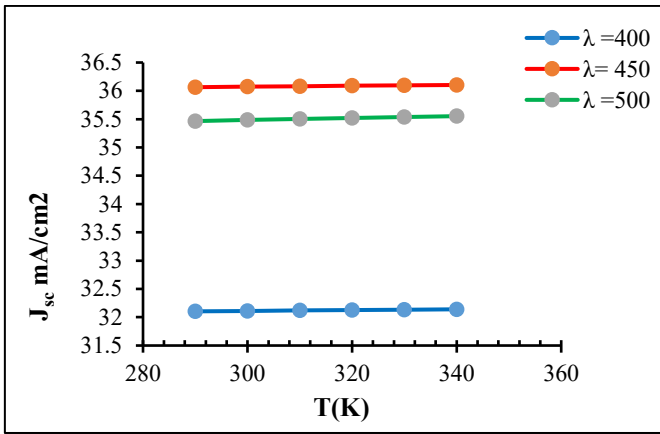
$$V_{oc} = \frac{nkT}{q} \ln \left( \frac{J_{sc}}{J_0} + 1 \right)$$

**Table 2.** Open-circuit voltage ( $V_{oc}$ ) at various temperatures and illumination wavelengths

Temperature (K)	$V_{oc}$ at $\lambda = 400$ (nm)	$V_{oc}$ at $\lambda = 450$ (nm)	$V_{oc}$ at $\lambda = 500$ (nm)
290	0.961939	0.821586	0.820658
300	0.883099	0.804181	0.803511
310	0.883099	0.792956	0.792489
320	0.780261	0.783384	0.782936
330	0.770009	0.773404	0.772924
340	0.760288	0.763616	0.763155

### 3.3 Short-circuit current density ( $J_{sc}$ ) characteristics and temperature influence

The short-circuit current density ( $J_{sc}$ ) increased slightly with temperature across all wavelengths (Table 3, Figure 4), attributed to enhanced carrier mobility and reduced non-radiative recombination at higher temperatures [37, 38]. The lowest increase occurred at 400 nm, linked to increased surface recombination due to shallower light penetration [37, 39].



**Figure 4.** The relationship between short-circuit current density ( $J_{sc}$ ) and temperature (T)

Carrier lifetime calculations are typically conducted for minority carriers. Consequently, the carrier lifetime is designated as the minority carrier lifetime. A reduced minority carrier lifetime indicates an increased recombination rate of excess carriers within the semiconductor.

**Table 3.** Short-circuit current density ( $J_{sc}$ ) at different temperatures and illumination wavelengths

Temperature (K)	$J_{sc}$ at $\lambda=400$ (nm)	$J_{sc}$ at $\lambda=450$ (nm)	$J_{sc}$ at $\lambda=500$ (nm)
290	32.10384	36.06397	35.46501
300	32.11215	36.07297	35.4839
310	32.11986	36.08133	35.50205
320	32.12703	36.08911	35.51952
330	32.13371	36.09637	35.53638
340	32.13995	36.10315	35.55266

### 3.4 Fill factor (FF %) as a function of temperature and wavelength

The FF % dependence versus temperature was studied under illumination at 400 nm, 450 nm, and 500 nm. The obtained results are organized in Table 4 and Figure 5, which unveils a nonlinear dependence where FF % increases with temperature until a maximum is achieved at peaking near 300 K and 310 K (~85%), then decreases with continued heating. This suggests the presence of an optimal thermal window that maximizes charge extraction and minimizes resistance and recombination losses.

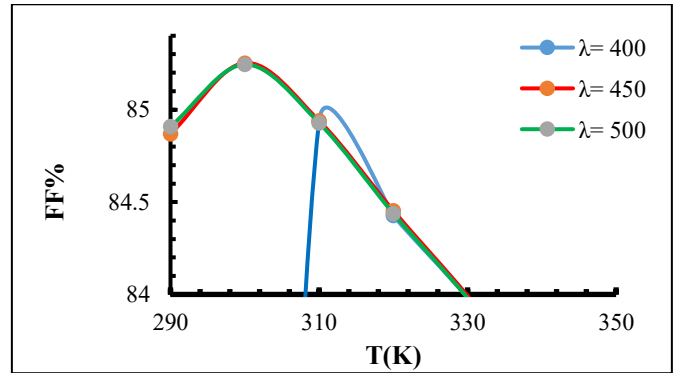
**Table 4.** Fill factor (FF %) values at various temperatures and wavelengths

Temperature (K)	FF at $\lambda=400$ (nm)	FF at $\lambda=450$ (nm)	FF at $\lambda=500$ (nm)
290	72.2214	84.8691	84.9088
300	77.3167	85.2526	85.2448
310	84.9348	84.9397	84.9288
320	84.427	84.4532	84.4386
330	83.9817	83.9931	83.9807
340	83.4619	83.4956	83.4796

At 290 K, FF % at 400 nm (72.22%) was further reduced compared with 450 nm (84.87%) and 500 nm (84.91%) due to more significant surface recombination at shorter wavelengths with a shallow optical penetration depth [34]. FF % was also enhanced with temperature and reached the maximum value

of ~84.93% at 310 K for all wavelengths, which is due to the increased carrier mobility and decrease in the series resistance [35].

For temperatures above 310K, FF % decreased somewhat to (83.46 % – 83.50%) at 340K, which is attributed to higher ion migration, deterioration of the interface, and non-radiative recombination processes [36].



**Figure 5.** The relationship between fill factor (FF) and temperature (T)

### 3.5 Temperature dependence of power conversion efficiency (PCE)

The power conversion efficiency (PCE) of the solar cell was evaluated across a temperature range from 290 K to 340 K under three illumination wavelengths (400 nm, 450 nm, and 500 nm). As shown in Figure 6 and summarized in Table 5, PCE decreases consistently with increasing temperature for all wavelengths.

Specifically, PCE declines by approximately 8–9% when the temperature rises from 290 K to 340 K, reflecting the detrimental effect of thermal stress on device performance [34, 39].

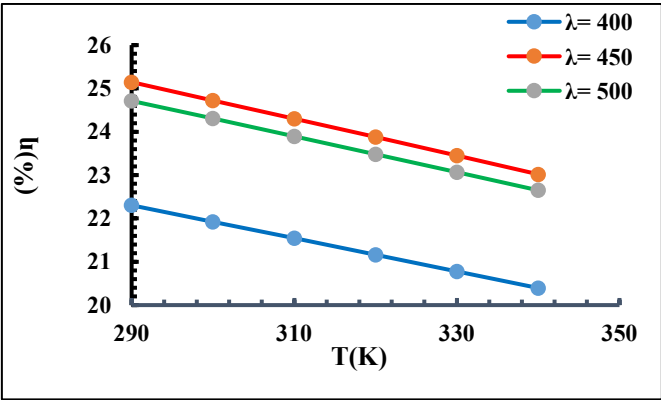
Of the wavelengths examined, 450 nm illumination yields the highest efficiency, reaching 25.15% at 290 K. This phenomenon is due to the beneficial overlap between the photon energy at this wavelength and the absorption spectrum of the perovskite active layer. This results in optimal charge carrier generation and minimal recombination losses, thereby enhancing photovoltaic performance [37, 40].

Conversely, 400 nm light exhibits the lowest power conversion efficiency values despite possessing higher photon energy. This occurs primarily because shorter-wavelength photons exhibit limited penetration depth, resulting in the generation of charge carriers near the surface, where surface recombination and defect-induced trapping are more pronounced. This reduces the effective carrier collection efficiency [41]. The performance at 500 nm lies between that of the other two wavelengths. Photons at 500 nm exhibit greater penetration into the absorber layer, facilitating the generation of bulk carriers. Nonetheless, due to their lower energy compared to 450 nm photons, the PCE is marginally reduced [41].

The reduction in PCE with increasing temperature is fundamentally associated with enhanced trap-assisted recombination caused by thermal energy, which reduces the open-circuit voltage ( $V_{oc}$ ) and fill factor (FF) [35, 38]. Increased reverse saturation current density ( $J_0$ ) leading to higher recombination rates [34]. Thermal effects cause variations in series resistance ( $R_s$ ) and shunt resistance ( $R_{sh}$ ),



increasing resistive losses and further degrading efficiency [42].



**Figure 6.** The relationship between power conversion efficiency (PCE) and temperature (T)

**Table 5.** Power conversion efficiency (PCE) values at various temperatures and illumination wavelengths

Temperature (K)	$\eta$ at $\lambda=400$ (nm)	$\eta$ at $\lambda=450$ (nm)	$\eta$ at $\lambda=500$ (nm)
290	22.3034	25.1464	24.7124
300	21.9256	24.7253	24.3048
310	21.5456	24.302	23.8947
320	21.1637	23.8763	23.482
330	20.7798	23.4484	23.0669
340	20.3944	23.0189	22.6499

Overall, these findings highlight the critical influence of both spectral illumination and temperature on perovskite solar cell performance. Engineering the device to optimize spectral response and improve thermal stability is essential for enhancing real-world operational efficiency [43, 44].

3.6 Temperature and light spectrum range effect on carrier lifetime and resistances

The lifetime of the minority carrier has a big effect on the recombination rates and the overall efficiency of perovskite solar cells. This study did not directly assess carrier lifetime; however, its effects were integrated into the SCAPS-1D simulation via recombination parameters aligned with experimental literature [44, 45]. Longer carrier lifetimes are linked to lower recombination losses, which improve the short-circuit current density ( $J_{sc}$ ) and fill factor (FF) [46]. The observed decrease in fill factor (FF) and alteration of the current-voltage (I-V) characteristics at elevated temperatures signify an increase in series resistance ( $R_s$ ) and shunt resistance ( $R_{sh}$ ). The resistances are mainly caused by interface degradation, ion migration, and defect formation due to heat, which speed up recombination and slow down charge transport [44, 47]. Resistive losses increase as the series resistance ( $R_s$ ) goes up. This lowers the fill factor and the power conversion efficiency (PCE) when the temperature rises.

4. CONCLUSION

This study comprehensively investigated the effects of temperature and illumination wavelength on the photovoltaic performance of the FTO/CdS/CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub>/CuO perovskite

solar cell using high-precision SCAPS-1D simulations. The results demonstrated that the open-circuit voltage ( $V_{oc}$ ) is significantly influenced by temperature, exhibiting a decrease of approximately 20% as the temperature increased from 290 K to 340 K. This decline is primarily attributed to the rise in reverse saturation current and enhanced trap-assisted recombination processes induced by thermal activation.

Conversely, a slight improvement in the short-circuit current density ( $J_{sc}$ ) was observed with increasing temperature, which can be ascribed to enhanced carrier mobility and a reduction in non-radiative recombination. The fill factor (FF) displayed a non-linear dependence on temperature, reaching its maximum near 310 K, reflecting a balance between improved charge transport and thermal degradation effects, such as ion migration and interface deterioration.

Regarding power conversion efficiency (PCE), a steady decline was noted with rising temperature, with optimal performance achieved at 450 nm illumination and lower temperatures, underscoring the critical importance of precise control over operational conditions to maximize device efficiency.

These findings highlight the necessity for advanced interface engineering to mitigate ion migration and trap-related recombination, spectral optimization to enhance carrier generation, and the development of thermally stable materials and device architectures. Additionally, supplementary experimental studies—such as carrier lifetime assessments and comprehensive resistive parameter analyses—are highly advisable to enhance comprehension and enable the practical implementation of perovskite solar cells in realistic operating conditions.

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